



EC4402C

Small Signal Switch, Interface Applications

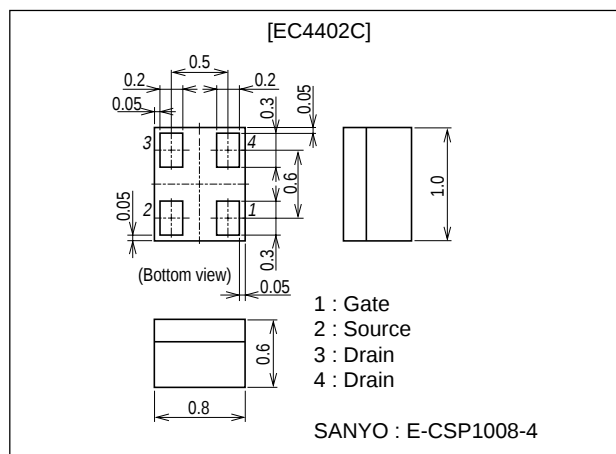
Features

- Low ON-resistance.
- Ultrahigh-speed switching.
- 2.5V drive.

Package Dimensions

unit : mm

2197



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		50	V
Gate-to-Source Voltage	V _{GSS}		±10	V
Drain Current (DC)	I _D		0.1	A
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	0.4	A
Allowable Power Dissipation	P _D		0.15	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{sta}		-55 to +150	°C

Electrical Characteristics at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D=1mA, V_{GS}=0$	50			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS}=50V, V_{GS}=0$			10	μA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 8V, V_{DS}=0$			± 10	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS}=10V, I_D=100\mu A$	0.4		1.3	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS}=10V, I_D=50mA$	0.13	0.18		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)1}$	$I_D=50mA, V_{GS}=4V$		6	7.8	Ω
	$R_{DS(on)2}$	$I_D=30mA, V_{GS}=2.5V$		7.1	9.9	Ω
	$R_{DS(on)3}$	$I_D=10mA, V_{GS}=1.5V$		10	20	Ω

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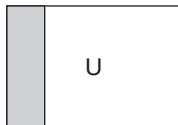
SANYO Electric Co.,Ltd. Semiconductor Company

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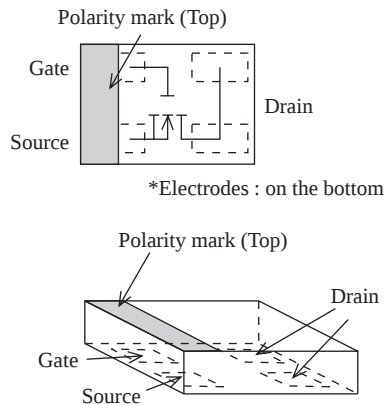
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Input Capacitance	Ciss	$V_{DS}=10V, f=1MHz$		6.6		pF
Output Capacitance	Coss	$V_{DS}=10V, f=1MHz$		4.7		pF
Reverse Transfer Capacitance	Crss	$V_{DS}=10V, f=1MHz$		1.7		pF
Turn-ON Delay Time	$t_d(on)$	See specified Test Circuit.		18		ns
Rise Time	t_r	See specified Test Circuit.		42		ns
Turn-OFF Delay Time	$t_d(off)$	See specified Test Circuit.		190		ns
Fall Time	t_f	See specified Test Circuit.		105		ns
Total Gate Charge	Qg	$V_{DS}=10V, V_{GS}=10V, I_D=100mA$		1.57		nC
Gate-to-Source Charge	Qgs	$V_{DS}=10V, V_{GS}=10V, I_D=100mA$		0.20		nC
Gate-to-Drain "Miller" Charge	Qgd	$V_{DS}=10V, V_{GS}=10V, I_D=100mA$		0.32		nC
Diode Forward Voltage	V_{SD}	$I_S=100mA, V_{GS}=0$		0.9	1.2	V

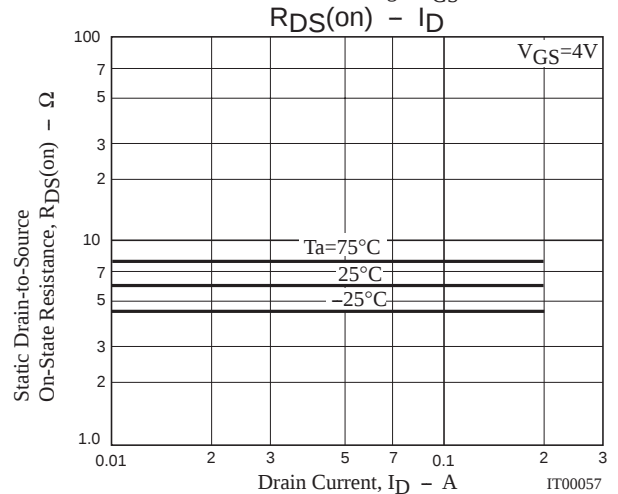
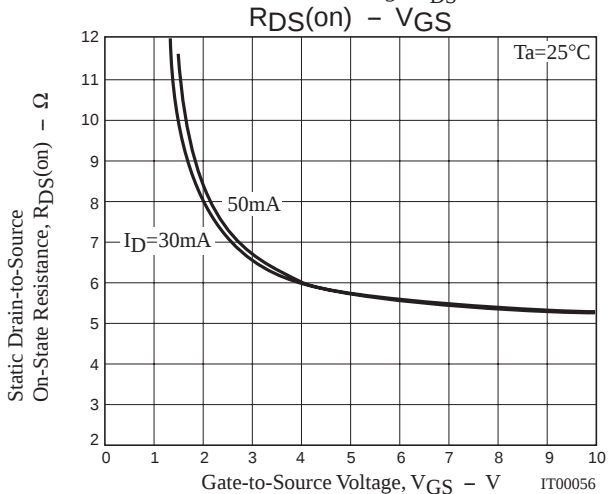
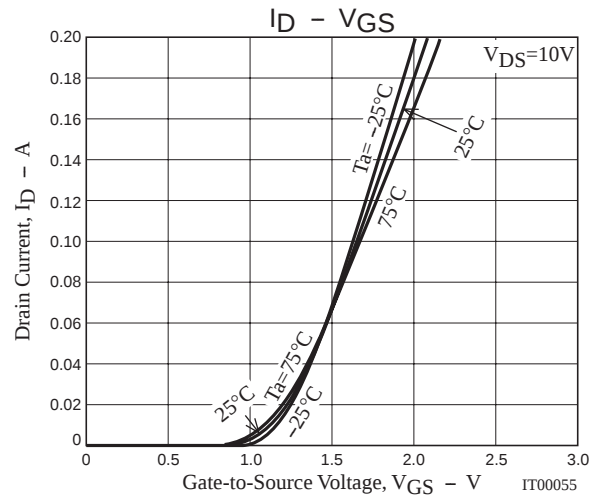
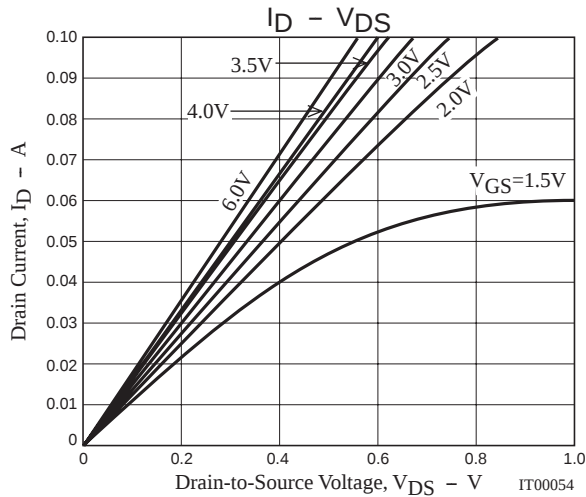
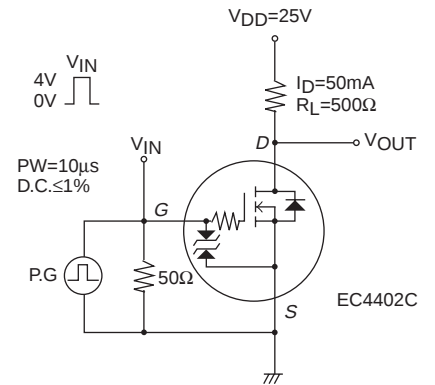
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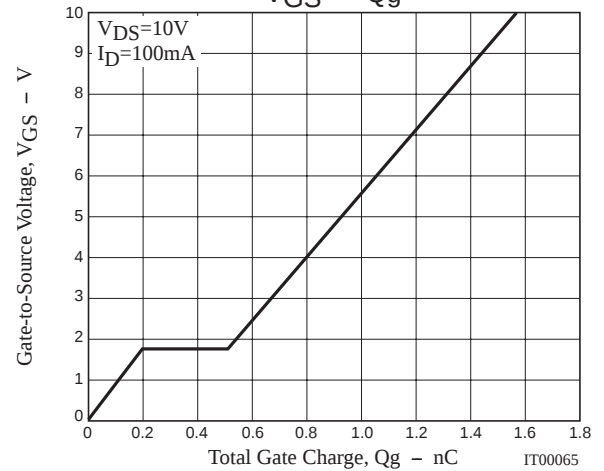
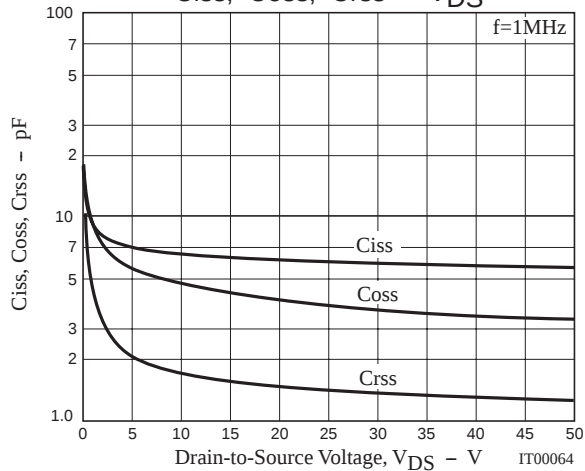
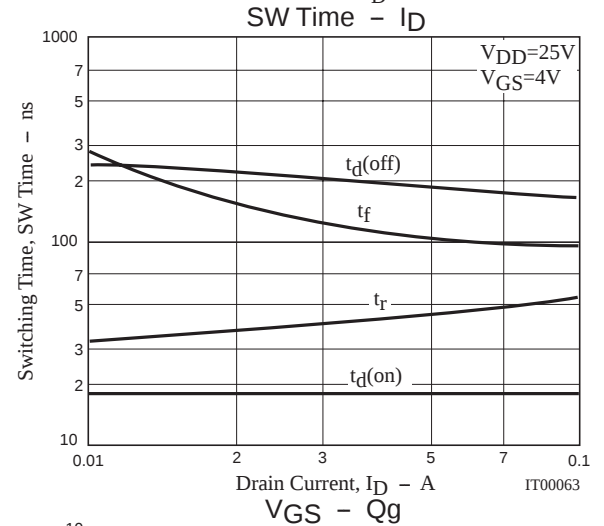
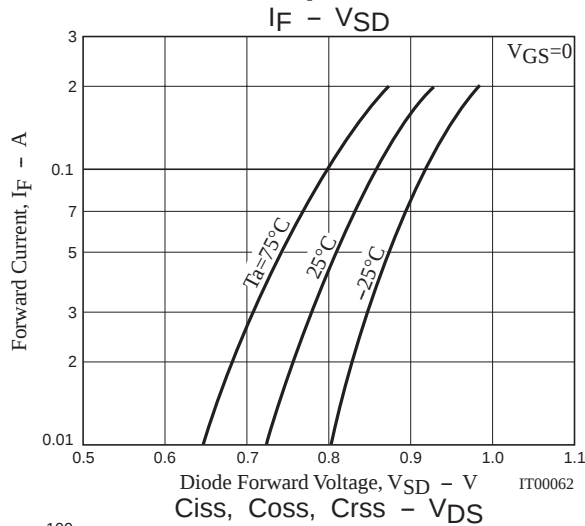
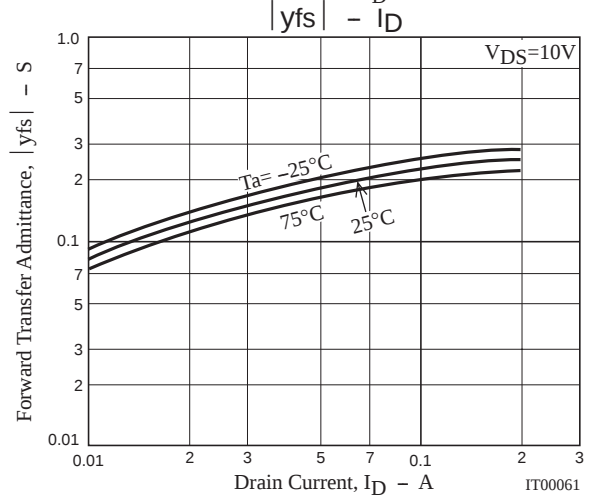
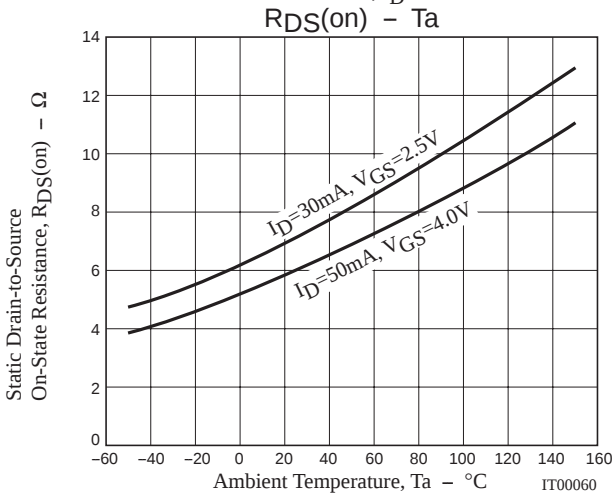
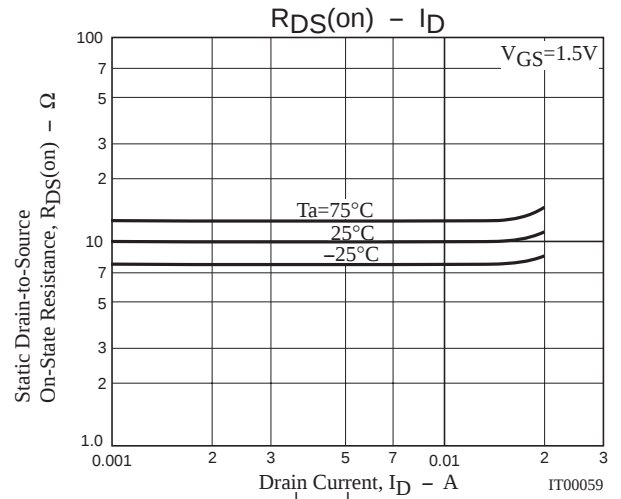
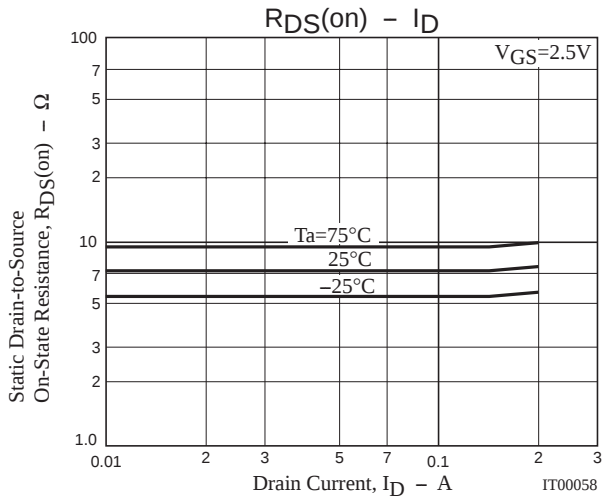


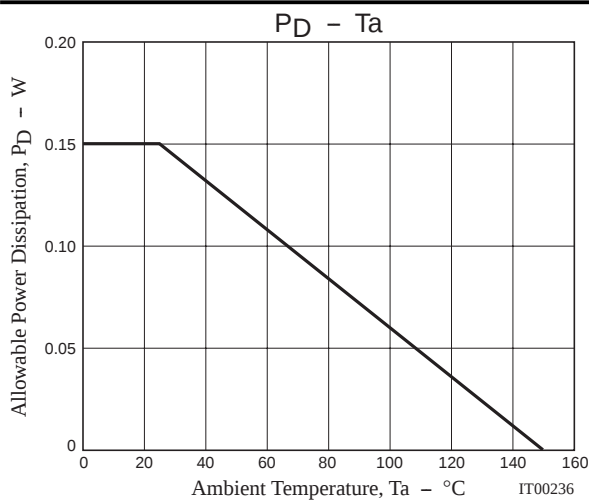
Electrical Connection(Top view)



Switching Time Test Circuit







Note on usage : Since the EC4402C is designed for high-speed switching applications, please avoid using this device in the vicinity of highly charged objects.

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